





30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(on)} | I _D Τ _A = +25°C |
|----------------------|--------------------------------|---|
| 30V | 460mΩ @ V _{GS} = 4.5V | 0.9A |
| 30V | 560mΩ @ V _{GS} = 2.5V | 0.7A |

Features and Benefits

- 0.5mm ultra low profile package for thin application
- 0.6mm² package footprint, 10 times smaller than SOT23
- Low V_{GS(th)}, can be driven directly from a battery
- Low R_{DS(on)}
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- ESD Protected Gate 2kV
- Qualified to AEC-Q101 Standards for High Reliability

Description and Applications

This MOSFET is designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Load Switch
- Portable Applications
- Power Management Functions

Mechanical Data

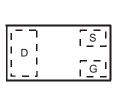
- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208@4)
- Weight: 0.001 grams (Approximate)



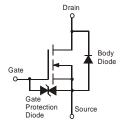




Bottom View



Top View Internal Schematic



Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|---------|--------------------|-----------------|-------------------|
| DMN3730UFB-7 | NE | 7 | 8 | 3,000 |
| DMN3730UFB-7B | NE | 7 | 8 | 10,000 |

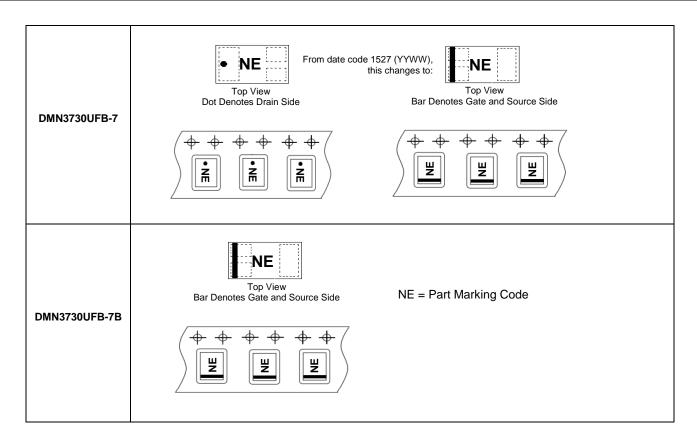
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

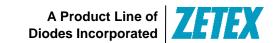




Marking Information







Maximum Ratings (@T_A = +25°C unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|-------------------------------|---------------------|---------------------------------------|-----------|-------|------|
| Drain-Source Voltage | | | V_{DSS} | 30 | V |
| Gate-Source Voltage | Gate-Source Voltage | | | ±8 | V |
| | | (Note 6) | 1 | 0.91 | |
| Continuous Drain Current | $V_{GS} = 4.5V$ | $T_A = +70^{\circ}C \text{ (Note 6)}$ | ID | 0.73 | Α |
| | | (Note 5) | | 0.75 | |
| Pulsed Drain Current (Note 7) | | I _{DM} | 3 | A | |

| Characteristic | Symbol | Value | Unit | | |
|---|----------|-----------------|-------------|------|--|
| Power Dissipation | (Note 6) | Б | 0.69 | - W | |
| Power Dissipation | (Note 5) | P_{D} | 0.47 | | |
| Thermal Desigtance Junction to Ambient | (Note 6) | Б | 180 | °C/W | |
| Thermal Resistance, Junction to Ambient | (Note 5) | $R_{\theta JA}$ | 258 | | |
| Operating and Storage Temperature Range | | T_J, T_{STG} | -55 to +150 | °C | |

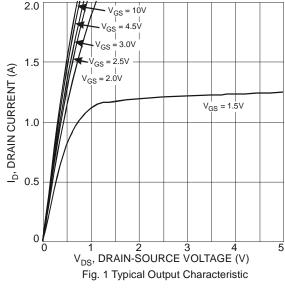
Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

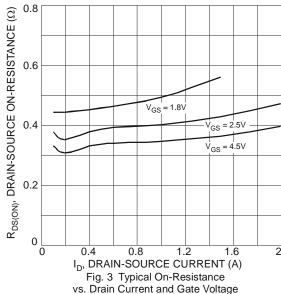
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|------|------|------|------|--|--|
| OFF CHARACTERISTICS | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | - | - | V | $V_{GS} = 0V, I_D = 10\mu A$ | |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | - | - | 1 | μA | V _{DS} = 30V, V _{GS} = 0V | |
| Gate-Source Leakage | I _{GSS} | - | - | 3 | μΑ | $V_{GS} = \pm 8V$, $V_{DS} = 0V$ | |
| ON CHARACTERISTICS | | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | 0.45 | - | 0.95 | V | $V_{DS} = V_{GS}$, $I_D = 250\mu A$ | |
| | | | | 460 | | $V_{GS} = 4.5V, I_D = 200mA$ | |
| Static Drain-Source On-Resistance (Note 8) | R _{DS} (ON) | - | - | 560 | mΩ | $V_{GS} = 2.5V, I_D = 100mA$ | |
| | | | | 730 | | $V_{GS} = 1.8V, I_D = 75mA$ | |
| Forward Transfer Admittance | Y _{fs} | 40 | - | - | mS | $V_{DS} = 3V, I_{D} = 10mA$ | |
| Diode Forward Voltage (Note 8) | V _{SD} | - | 0.7 | 1.2 | V | $V_{GS} = 0V, I_{S} = 300mA$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | • | |
| Input Capacitance | C _{iss} | - | 64.3 | - | pF | | |
| Output Capacitance | Coss | • | 6.1 | - | рF | $V_{DS} = 25V, V_{GS} = 0V,$ - f = 1.0MHz | |
| Reverse Transfer Capacitance | Crss | 1 | 4.5 | - | рF | 1 = 1.000112 | |
| Gate Resistance | Rg | - | 70 | - | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge | Qg | - | 1.6 | - | nC | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | |
| Gate-Source Charge | Q _{gs} | - | 0.2 | - | nC | $V_{GS} = 4.5V, V_{DS} = 15V,$ $I_{D} = 1A$ | |
| Gate-Drain Charge | Q_{gd} | - | 0.2 | - | nC | | |
| Turn-On Delay Time | t _{D(on)} | - | 3.5 | - | ns | V _{DS} = 10V, I _D = 1A | |
| Turn-On Rise Time | t _r | - | 2.8 | - | ns | | |
| Turn-Off Delay Time | t _{D(off)} | - | 38 | - | ns | $V_{GS} = 10V, R_G = 6\Omega$ | |
| Turn-Off Fall Time | t _f | - | 13 | - | ns | | |

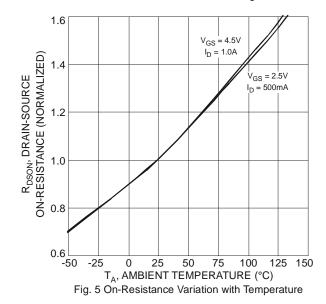
Notes:

- 5. For a device surface mounted on a minimum recommended pad layout of an FR4 PCB, in still air conditions; the device is measured when operating in steady-state condition.
- 6. Same as Note 5, except the device measured at $t \leq 10 \mbox{ seconds.}$
- 7. Same as Note 5, except the device is pulsed at duty cycle of 1% for a pulse width of 10µs.
- 8. Measured under pulsed conditions to minimize self-heating effect. Pulse width \leq 300 μ s; duty cycle \leq 2%.
- 9. For design aid only, not subject to production testing.



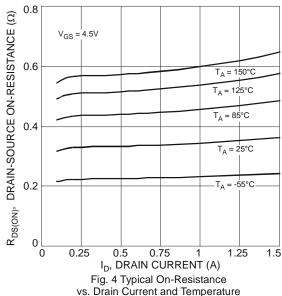


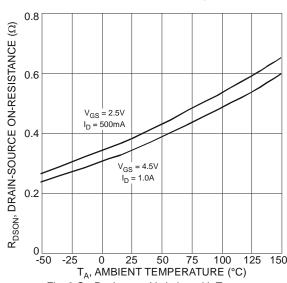




2.0

 $V_{DS} = 5V$







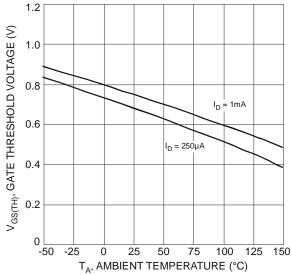
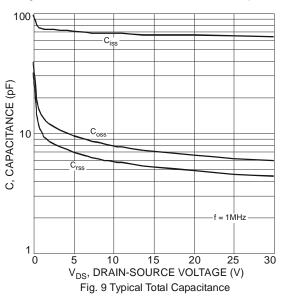
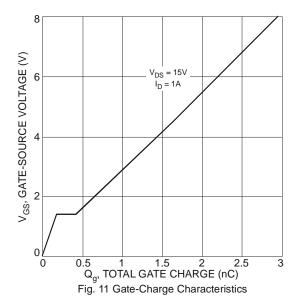
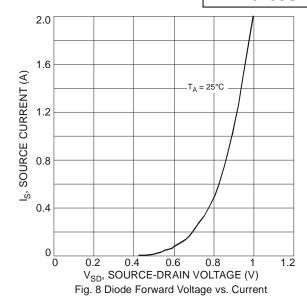
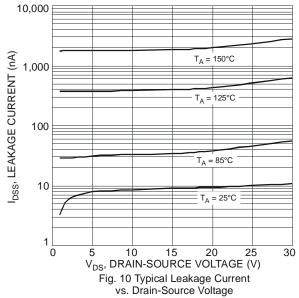


Fig. 7 Gate Threshold Variation vs. Ambient Temperature











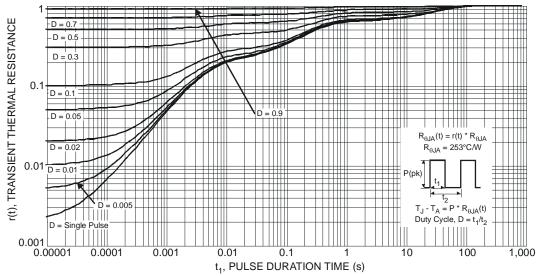


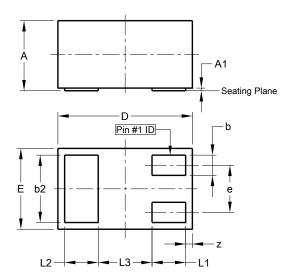
Fig. 12 Transient Thermal Response





Package Outline Dimensions

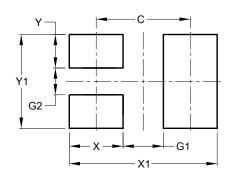
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| X1-DFN1006-3 | | | | | |
|----------------------|------|-------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.47 | 0.53 | 0.50 | | |
| A1 | 0.00 | 0.05 | 0.03 | | |
| b | 0.10 | 0.20 | 0.15 | | |
| b2 | 0.45 | 0.55 | 0.50 | | |
| D | 0.95 | 1.075 | 1.00 | | |
| E | 0.55 | 0.675 | 0.60 | | |
| е | ı | - | 0.35 | | |
| L1 | 0.20 | 0.30 | 0.25 | | |
| L2 | 0.20 | 0.30 | 0.25 | | |
| L3 | - | - | 0.40 | | |
| Z | 0.02 | 0.08 | 0.05 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 0.70 | | | |
| G1 | 0.30 | | | |
| G2 | 0.20 | | | |
| Х | 0.40 | | | |
| X1 | 1.10 | | | |
| Υ | 0.25 | | | |
| V1 | 0.70 | | | |





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